

INCHANGE SEMICONDUCTOR

isc Silicon PNP Power Transistors

3CD9C

DESCRIPTION

- With TO-3 packaging
- Large collector current
- · Low collector saturation voltage
- High power dissipation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

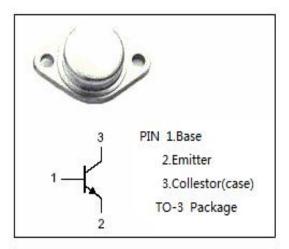
- Designed for use in DC-DC converter
- Driver of solenoid or motor

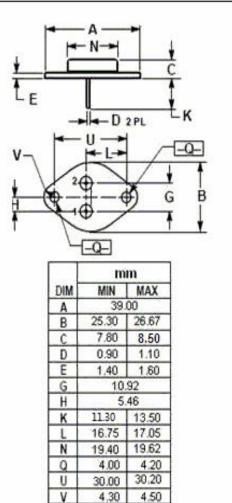
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|---|---------|------|
| V _{CBO} | Collector-Base Voltage | -80 | V |
| V _{CEO} | Collector-Emitter Voltage | -80 | V |
| V _{EBO} | Emitter-Base Voltage | -4 | V |
| lc | Collector Current-Continuous | -15 | А |
| Pc | Collector Power Dissipation@Tc=75°C 150 | | W |
| TJ | Junction Temperature | -55~150 | |
| T _{stg} | Storage Temperature | -55~150 | °C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | МАХ | UNIT |
|---------------------|--------------------------------------|------|--------------|
| R _{th j-c} | Thermal Resistance, Junction to Case | 0.66 | °C /W |





isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | MIN | МАХ | UNIT |
|----------------------|--------------------------------------|--|-----|------|------|
| V _{CEO(BR)} | Collector-Emitter Breakdown Voltage | I _C =- 10mA ; I _B = 0 | -80 | | V |
| V _{EBO(BR)} | Emitter-Base Breakdown Voltage | I _E =- 10mA ; I _C = 0 | -4 | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | Ic=- 7.5A; I _B = -1.5A | | -2 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = -7.5A; I _B = -1.5A | | -2 | V |
| I _{CEO} | Collector Cutoff Current | V _{CE} =- 80V; I _B = 0 | | -3.0 | mA |
| Ісво | Collector Cutoff Current | V _{CB} =- 80V; I _E = 0 | | -1.0 | mA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = -4V; I _C = 0 | | -1.0 | mA |
| h _{FE} | DC Current Gain | I _C = -7.5A; V _{CE} =-10V | 10 | 180 | |

NOTICE:

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